Accepted Manuscript

Negative differential resistance in heterojunction polymeric films

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PII: S0749-6036(17)31830-X

DOI: 10.1016/j.spmi.2017.10.010

Reference: YSPMI 5304

To appear in: Superlattices and Microstructures

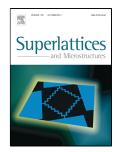
Received Date: 01 August 2017

Revised Date: 09 October 2017

Accepted Date: 09 October 2017

Please cite this article as: Sonika Rathi, Saral K. Gupta, Chandra Mohan Singh Negi, Amarjeet Singh, Negative differential resistance in heterojunction polymeric films, *Superlattices and Microstructures* (2017), doi: 10.1016/j.spmi.2017.10.010

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Highlights of the work

- For the first time, Negative Differential Resistance (NDR) is reported in purely polymeric systems (P3HT/PCBM).
- Simple construction, robust NDR and large current shown by these devices make them potential candidate for the development of organic memory elements.
- Room temperature FWHM of dI/dV curves is comparable or less with that of inorganic devices synthesised earlier.

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